

### **INCHANGE SEMICONDUCTOR**

# isc N-Channel MOSFET Transistor

### IXTA90N055T2

### • FEATURES

- Static drain-source on-resistance: RDs(on) ≤ 8.4mΩ@V<sub>GS</sub>=10V
- Fully characterized avalanche voltage and current
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

#### APPLICATION

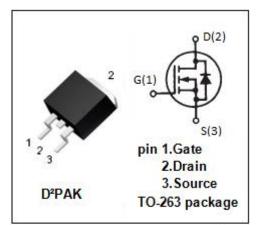
- DC/DC Converters
- High Current Switching Applications

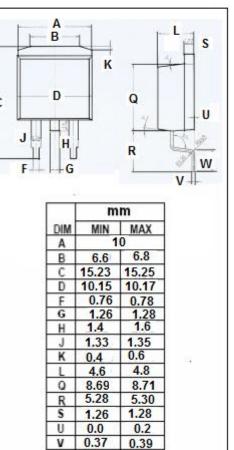
• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)					
SYMBOL	PARAMETER	VALUE	UNIT		
V <sub>DSS</sub>	Drain-Source Voltage	55	V		
V <sub>GS</sub>	Gate-Source Voltage	±20	V		
ID	Drain Current-Continuous	90	A		
I <sub>DM</sub>	Drain Current-Single Pulsed	230	A		
PD	Total Dissipation @Tc=25°C	150	W		
Tj	Operating Junction Temperature	-55~175	Ĉ		
T <sub>stg</sub>	Storage Temperature	-55~175	°C		

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT	
R <sub>th(j-c)</sub>	Junction-to-case thermal resistance	1.0	°C/W	

1





w

2.80

2.82



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### **ELECTRICAL CHARACTERISTICS**

#### $T_{\text{C}}\text{=}25^{\circ}\!\!\!\mathrm{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	МАХ	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; ID = 250 μ A	55		V
$V_{GS(th)}$	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> ; ID = 250 μ A	2.0	4.0	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> =10V; I <sub>D</sub> = 25A		8.4	mΩ
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> = ±20V;V <sub>DS</sub> =0V		±200	nA
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> = V <sub>DSS</sub> ; V <sub>GS</sub> = 0V		2	μ <b>Α</b>
		V <sub>DS</sub> = V <sub>DSS</sub> ; V <sub>GS</sub> = 0V;T <sub>J</sub> = 150°C		200	
V <sub>SD</sub>	Diode forward voltage	I <sub>F</sub> = 25A; V <sub>GS</sub> = 0V		1.0	V

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